

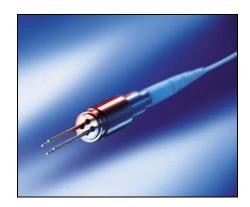


# Ternary PIN Photodiode with integrated Preamplifier IC

# SRP00244x SRP00245x

### Features

- InGaAs/InP PIN photodiode with preamplifier IC
- Designed for SONET OC-3 / SDH STM-1 applications in fiber-optics communication systems
- Sensitive receiver for 2nd and 3rd optical window (1300 nm and 1550 nm)
- Suitable for bit rates up to 155 Mbit/s
- Module with high optical sensitivity
- Fast switching times
- Low dark current
- Excellent noise immunity
- High reverse current stability from planar structure
- Hermetically sealed TO46 package

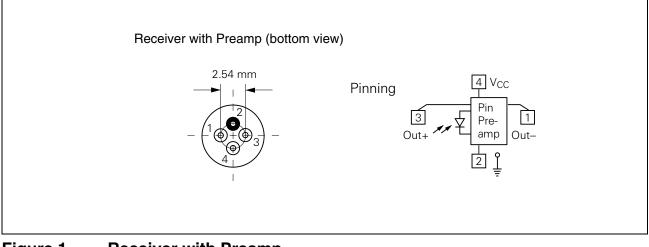






## **Pin Configuration**

# **Pin Configuration**







#### Description

## Description

The Infineon optical receiver module has been designed for use in optical networks and is suitable for bit rates up to max. 2.5 Gbit/s if used without any TIA.

The optical receiver module uses a high-speed PIN photodetector optional coupled with a hybrid low noise transimpedance amplifier (PIN-TIA). The optical receiver photodiode can be used for 1310 nm or 1550 nm optical communications.

The PIN photodiode is made of InGaAs/InP and has an active diameter of 75  $\mu$ m. The function of the PIN and PIN-TIA optical receiver module is to detect input optical power, to transduce the incident radiation into current (PIN) and then to convert the current into a voltage (PIN-TIA).

The low input noise current density of the used transimpedance amplifiers in PIN-TIA's provides the optical receiver module, when used with appropriate filtering, with ample sensitivity for realizing minimum input power requirements. Designers of optical receivers can use the module in any application that benefits from integration of the photodiode and TIA into a TO coaxial package. Typical for such applications are receivers for digital crossconnects, digital loop carriers, add/drop-multiplexers and optical network units.

Last but not least the fast switching times, low dark currents and the packaging in a compact and hermetically sealed TO46 make the optical receivers usable in many other fiber optic receiver applications. One application is the use in a Compact realization of a transceiver in one module like the so called BIDI<sup>®</sup> (Figure 2).

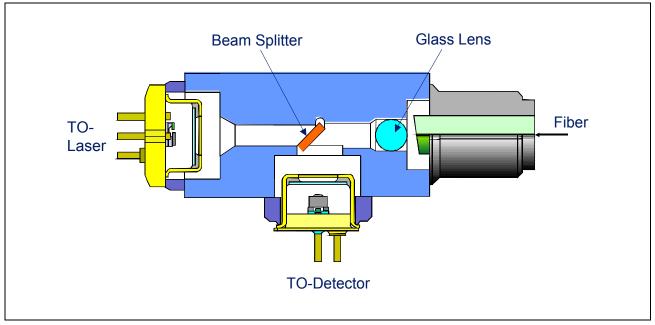


Figure 2 Compact Realization of the Transceiver in One Module



#### **Technical Data**

## **Technical Data**

### **Absolute Maximum Ratings**

Parameter	Symbol	Limit Values		Unit	
		min.	max.		
Module					
Operating temperature range at case	T <sub>C</sub>	-40	85	°C	
Storage temperature range	T <sub>stg</sub>	-40	85		
Soldering temperature ( $t_{max} = 10$ s, 2 mm distance from bottom edge of case)	T <sub>S</sub>		260		
Receiver Diode					
Reverse Voltage	$V_{R}$		20	V	
Forward Current	I <sub>F</sub>		10	mA	
Optical power into the optical port	P <sub>port</sub>		1	mW	

The electro-optical characteristics described in the following table are only valid for use within the specified maximum ratings or under the recommended operating conditions. Characteristics for Pin-Preamp Receivers at  $T_A = 25^{\circ}$ C, unless otherwise specified.

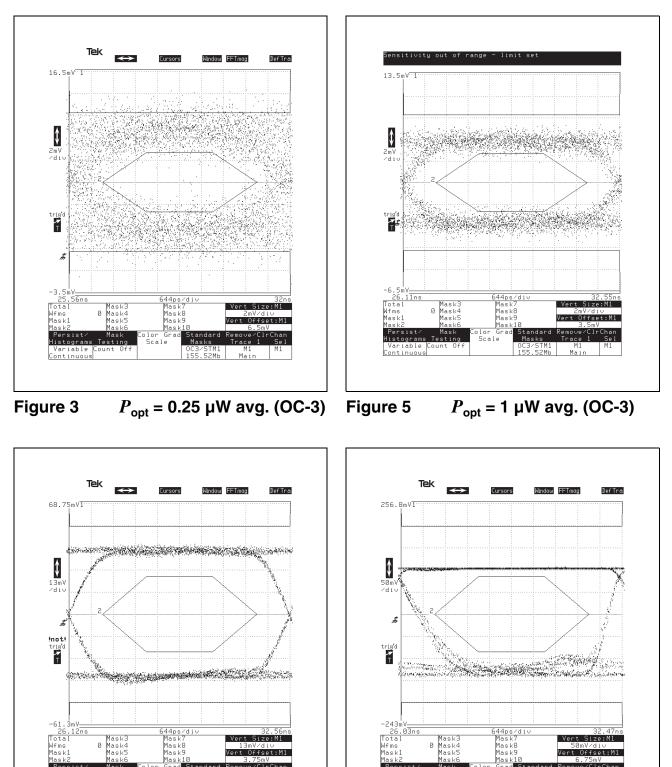
#### Preamp Characteristics

Parameter	Symbol	Limit Values			Unit
		min.	typ.	max.	
DC-Characteristics					
Supply Voltage	V <sub>CC</sub>	4.5	5	5.5	V
Supply Current	I <sub>CC</sub>		25	26	mA
AC-Characteristics		·	·		·
Optical Sensitivity (BER $\leq 10^{-9}$ , PN23)	S	-31	-35		dBm
Linear Bandwidth (-3 dB)	BW	180	240		MHz
Optical overload (avg.)	P <sub>max</sub>	-4			dBm
Transimpedance (single ended)	R <sub>T</sub>	8	10	12	kΩ
Output resistance	R <sub>out</sub>	40	50	60	Ω
Noise current density			3		pa/√Hz
Gain (differential)	G	10		24	V/mW
Return Loss, $\lambda = 1310$ nm	RL			-27	dB



### **Technical Data**

### Some Eye Diagrams



 $P_{\rm opt}$  = 10 µW avg. (OC-3)

155.52Mb

Mai

Figure 6 P

ontinuous

Ma

155.52M

Figure 4

ariabie ntinuous



**Fiber Data** 

## **Fiber Data**

The mechanical fiber characteristics are described in the following table.

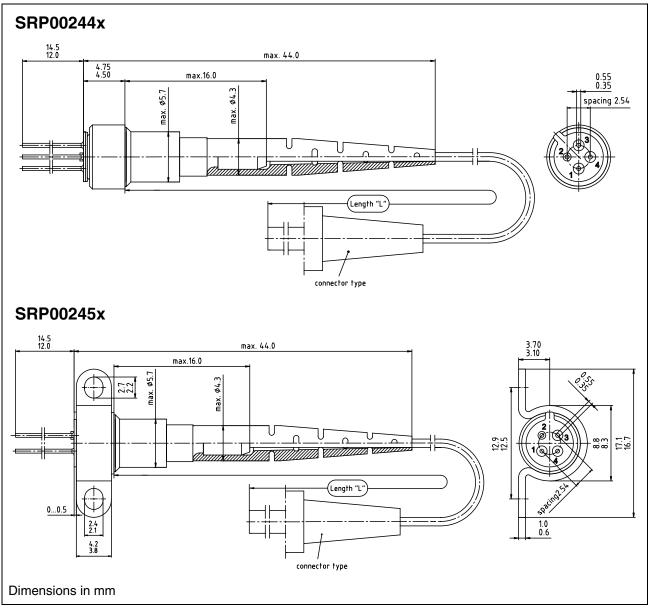
## **Fiber Characteristics**

Parameter	Limit Values			Unit
	min.	typ.	max.	
Mode Field Diameter		50		μm
Cladding Diameter	123	125	127	
Mode Field/Cladding Concentricity Error			1	
Cladding Non-circularity			2	%
Mode Field Non-circularity			6	
Cut off Wavelength	1270			nm
Jacket Diameter	0.8		1	mm
Bending Radius	30			
Tensile Strength Fiber Case	5			Ν
Length	0.8		1.2	m



## **Package Outlines**

## Package Outlines







## Package Outlines

# Flange Options

Туре	Flange
SRP00244x	without
SRP00245x	with

### **Connector Options**

Model	Туре
SRP00244H SRP00245H	MM FC/PC
SRP00244G SRP00245G	SM FC/PC
SRP00244O SRP00245O	MM SC/PC 0°
SRP00244N SRP00245N	SM SC/PC 0°
SRP00244Q SRP00245Q	MM SC 8° APC
SRP00244P SRP00245P	SM SC 8° APC
SRP00244W SRP00245W	MM without connector
SRP00244Z SRP00245Z	SM without connector

Other connectors on request

SRP002 SRP002 Revision		2001-12-01	DS0
Previous	s Version:		
Page	Subjects	(major changes since last revision)	
	Documen	t's layout has been changed: 2002-Aug.	

For questions on technology, delivery and prices please contact the Infineon Technologies Offices in Germany or the Infineon Technologies Companies and Representatives worldwide: see our webpage at http://www.infineon.com.

Edition 2001-12-01

Published by Infineon Technologies AG, St.-Martin-Strasse 53, D-81541 München, Germany © Infineon Technologies AG 2002. All Rights Reserved.

#### **Attention please!**

The information herein is given to describe certain components and shall not be considered as warranted characteristics.

Terms of delivery and rights to technical change reserved.

We hereby disclaim any and all warranties, including but not limited to warranties of non-infringement, regarding circuits, descriptions and charts stated herein.

Infineon Technologies is an approved CECC manufacturer.

#### Information

For further information on technology, delivery terms and conditions and prices please contact your nearest Infineon Technologies Office in Germany or our Infineon Technologies Representatives worldwide.

#### Warnings

Due to technical requirements components may contain dangerous substances. For information on the types in question please contact your nearest Infineon Technologies Office.

Infineon Technologies Components may only be used in life-support devices or systems with the express written approval of Infineon Technologies, if a failure of such components can reasonably be expected to cause the failure of that life-support device or system, or to affect the safety or effectiveness of that device or system. Life-support devices or systems are intended to be implanted in the human body, or to support and/or maintain and sustain and/or protect human life. If they fail, it is reasonable to assume that the health of the user or other persons may be endangered.